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## RSS050P03

### Transistors

# Switching (−30V, −5.0A)

## RSS050P03

#### ●Features

- 1) Low On-resistance.
- 2) Built-in G-S Protection Diode.
- 3) Small and Surface Mount Package (SOP8).

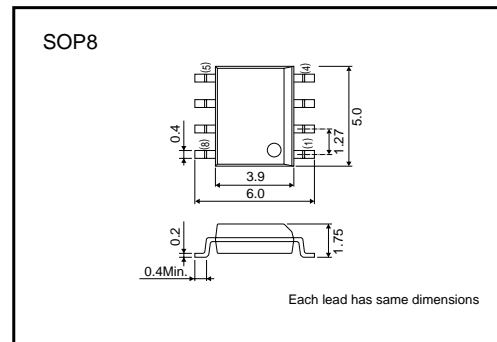
#### ●Application

Power switching, DC / DC converter.

#### ●Structure

Silicon P-channel  
 MOS FET

#### ●External dimensions (Unit : mm)



#### ●Packaging specifications

Type	Package	Taping
	Code	TB
	Basic ordering unit (pieces)	2500
RSS050P03		○

#### ●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Drain-source voltage	$V_{DSS}$	−30	V
Gate-source voltage	$V_{GSS}$	±20	V
Drain current	Continuous	$I_D$	±5.0 A
	Pulsed	$I_{DP}$	±20 A *1
Source current (Body diode)	Continuous	$I_S$	−1.6 A
	Pulsed	$I_{SP}$	−20 A *1
Total power dissipation	$P_D$	2.0	W *2
Channel temperature	$T_{ch}$	150	°C
Range of Storage temperature	$T_{stg}$	−55 to +150	°C

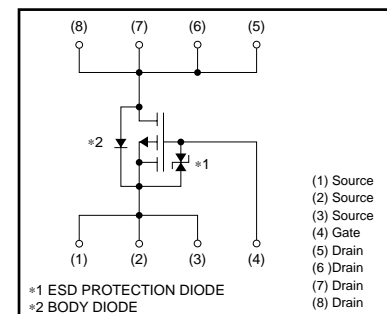
\*1  $P_w \leq 10\mu s$ , Duty cycle  $\leq 1\%$   
 \*2 Mounted on a ceramic board

#### ●Thermal resistance (Ta=25°C)

Parameter	Symbol	Limits	Unit
Channel to ambient	$R_{th}(ch-a)$	62.5	°C / W *

\* Mounted on a ceramic board.

#### ●Equivalent circuit



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#### ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I <sub>GSS</sub>	–	–	±10	μA	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V
Drain-source breakdown voltage	V <sub>(BR) DSS</sub>	–30	–	–	V	I <sub>D</sub> = –1mA, V <sub>GS</sub> =0V
Zero gate voltage drain current	I <sub>DSS</sub>	–	–	–1	μA	V <sub>DS</sub> = –30V, V <sub>GS</sub> =0V
Gate threshold voltage	V <sub>GS (th)</sub>	–1.0	–	–2.5	V	V <sub>DS</sub> = –10V, I <sub>D</sub> = –1mA
Static drain-source on-state resistance	R <sub>DS (on)</sub> *	–	30	42	mΩ	I <sub>D</sub> = –5.0A, V <sub>GS</sub> = –10V
		–	47	65	mΩ	I <sub>D</sub> = –2.5A, V <sub>GS</sub> = –4.5V
		–	55	77	mΩ	I <sub>D</sub> = –2.5A, V <sub>GS</sub> = –4.0V
Forward transfer admittance	Y <sub>fs</sub>   *	5.0	–	–	S	V <sub>DS</sub> = –10V, I <sub>D</sub> = –2.5A
Input capacitance	C <sub>iss</sub>	–	1200	–	pF	V <sub>DS</sub> = –10V
Output capacitance	C <sub>oss</sub>	–	250	–	pF	V <sub>GS</sub> =0V
Reverse transfer capacitance	C <sub>rss</sub>	–	180	–	pF	f=1MHz
Turn-on delay time	t <sub>d (on)</sub> *	–	12	–	ns	I <sub>D</sub> = –2.5A
Rise time	t <sub>r</sub> *	–	25	–	ns	V <sub>DD</sub> ≐ –15V V <sub>GS</sub> = –10V
Turn-off delay time	t <sub>d (off)</sub> *	–	70	–	ns	R <sub>L</sub> =6Ω
Fall time	t <sub>f</sub> *	–	35	–	ns	R <sub>GS</sub> =10Ω
Total gate charge	Q <sub>g</sub>	–	13	–	nC	V <sub>DD</sub> ≐ –15V
Gate-source charge	Q <sub>gs</sub>	–	2.8	–	nC	V <sub>GS</sub> = –5V
Gate-drain charge	Q <sub>gd</sub>	–	5.0	–	nC	I <sub>D</sub> = –5.0A

\*Pulsed

#### Body diode characteristics (source-drain characteristics)

Forward voltage	V <sub>SD</sub>	–	–	–1.2	V	I <sub>S</sub> = –1.6A, V <sub>GS</sub> =0V
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● **Electrical characteristic curves**

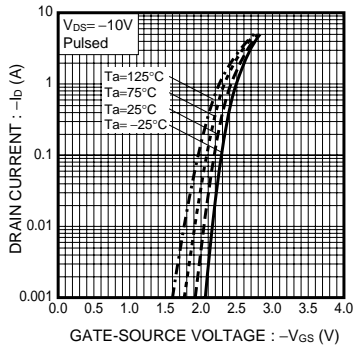


Fig.1 Typical Transfer Characteristics

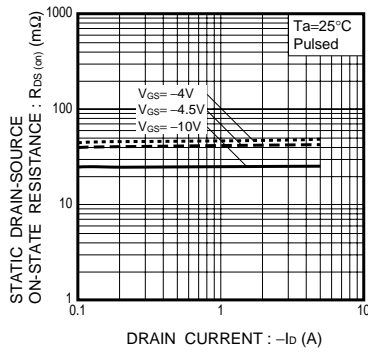


Fig.2 Static Drain-Source On-State Resistance vs. Drain Current

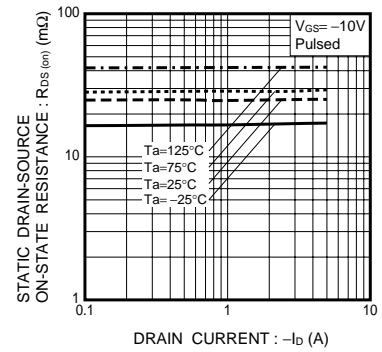


Fig.3 Static Drain-Source On-State Resistance vs. Drain Current

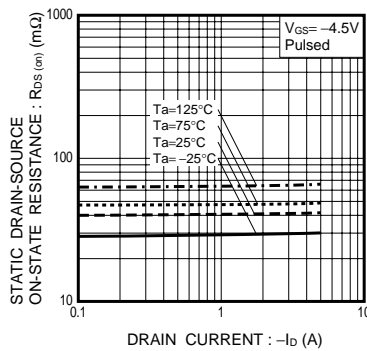


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current

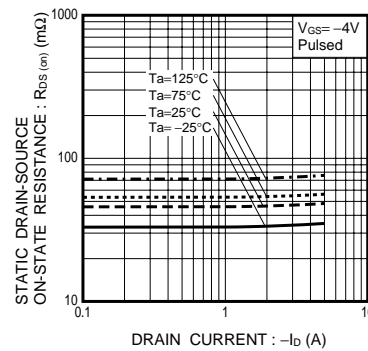


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current

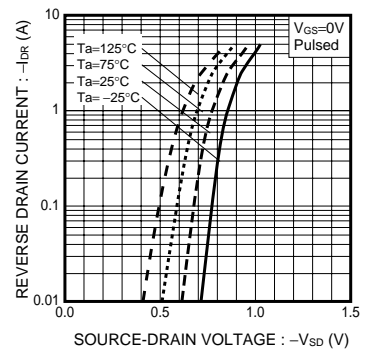


Fig.6 Reverse Drain Current Source-Drain Current

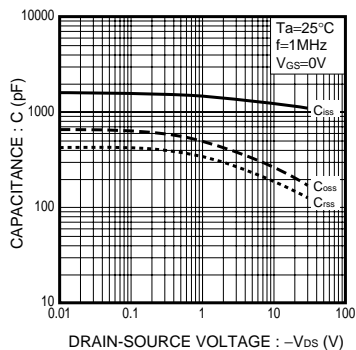


Fig.7 Typical Capacitance vs. Drain-Source Voltage

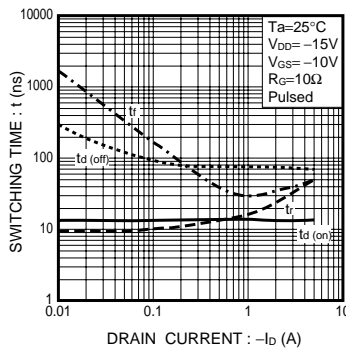


Fig.8 Switching Characteristics

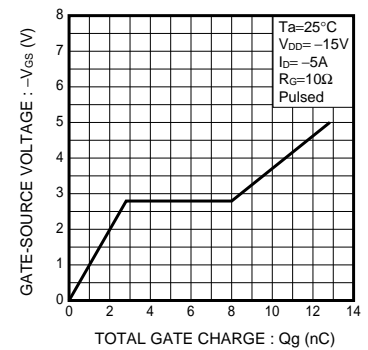


Fig.9 Dynamic Input Characteristics

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● **Measurement circuits**

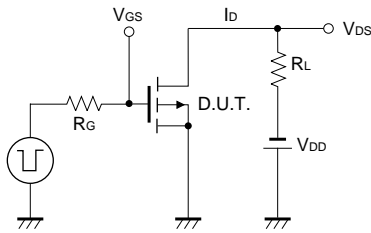


Fig.10 Switching Time Test Circuit

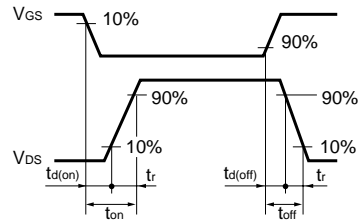


Fig.11 Switching Time Waveforms

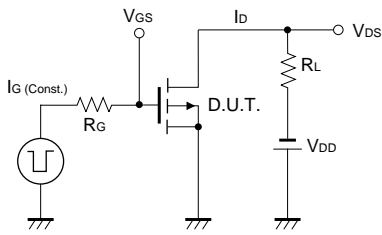


Fig.12 Gate Charge Test Circuit

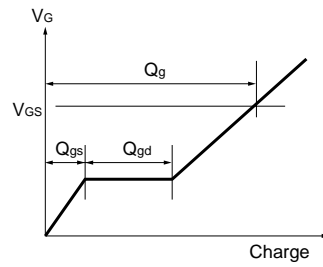


Fig.13 Gate Charge Waveform

## Appendix

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